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PRODUCT RELIABILITY REPORT
FOR

DS28E17

Maxim Integrated Products

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Prepared by:

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Conclusion:

The following qualification successfully meets the quality and reliability standards required of all Maxim products:

DS28E17

In addition, Maxim's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at http://www.maxim-ic.com/TechSupport /dsreliability.html.

Device Description:

A description of this device can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l_datasheet3.cfm.

Reliability Derating:

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

AfT = exp((Ea/k)*(1/Tu - 1/Ts)) = tu/ts
AfT = Acceleration factor due to Temperature
tu = Time at use temperature (e.g. 55°C)
ts = Time at stress temperature (e.g. 125°C)
k = Boltzmann's Constant (8.617 x 10-5 eV/°K)
Tu = Temperature at Use (°K)
Ts = Temperature at Stress (°K)
Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

AfV = exp(B*(Vs - Vu))
AfV = Acceleration factor due to Voltage
Vs = Stress Voltage (e.g. 7.0 volts)
Vu = Maximum Operating Voltage (e.g. 5.5 volts)
B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

Fr = X/(ts * AfV * AfT * N * 2)
X = Chi-Sq statistical upper limit
N = Life test sample size

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

MTTF = 1/Fr

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

FAILURE RATE:	**MTTF (YRS):**	**55079**	**FITS:**	**2.1**
	DEVICE HOURS:	**442104589**	**FAILS:**	**0**

Only data from Operating Life or similar stresses are used for this calculation.

The parameters used to calculate this failure rate are as follows:

Cf: 60% **Ea: 0.7** **B: 0** **Tu: 25** **°C** **Vu: 3.6** **Volts**

The reliability data follows. At the start of this data is the device information. The next section is the detailed reliability data for each stress. The reliability data section includes the latest data available and may contain some generic data. **Bold** Product Number denotes specific product data.

Device Information:

Process:	TSMC 0.18um Mixed signal, Embedded Flash, General Purpose, Two Poly Five Metal, 1.8V/3.3V Polyimide - No
Passivation:	SiO/SiN
Die Size:	83 x 72
Number of Transistors:	4588269
Interconnect:	Aluminum / 0.5% Copper
Gate Oxide Thickness:	32 Å

ESD HBM

DESCRIPTION	DATE CODE/PRODUCT/LOT			CONDITION	READPOIN		QTY	FAILS	FA#
ESD SENSITIVITY	1211	**MAXQ615**	ZS123275AE	JESD22-A114 HBM 500 VOLTS	1	PUL'S	5	0	
ESD SENSITIVITY	1211	**MAXQ615**	ZS123275AE	JESD22-A114 HBM 1000 VOLTS	1	PUL'S	5	0	
ESD SENSITIVITY	1211	**MAXQ615**	ZS123275AE	JESD22-A114 HBM 1500 VOLTS	1	PUL'S	5	0	
ESD SENSITIVITY	1211	**MAXQ615**	ZS123275AE	JESD22-A114 HBM 2000 VOLTS	1	PUL'S	5	0	
ESD SENSITIVITY	1211	**MAXQ615**	ZS123275AE	JESD22-A114 HBM 2500 VOLTS	1	PUL'S	5	0	
					Total:			**0**	

LATCH-UP

DESCRIPTION	DATE CODE/PRODUCT/LOT			CONDITION	READPOIN	QTY	FAILS	FA#
LATCH-UP I	1211	**MAXQ615**	ZS123275AE	JESD78A, I-TEST 25C 100mA		6	0	
LATCH-UP V	1211	**MAXQ615**	ZS123275AE	JESD78A, V-SUPPLY TEST 25C		6	0	
					Total:		**0**	

OPERATING LIFE

DESCRIPTION	DATE CODE/PRODUCT/LOT	CONDITION	READPOIN	QTY	FAILS	FA#

HIGH TEMP OP LIFE	0851	MAXQ610	QJ091123AB	125C, 3.6V (PSA) & 2.0V (PSB)	1000	HRS	77	0
HIGH TEMP OP LIFE	0946	MAXQ622	QN091481C	125C, 3.6V (PSA) & 5.5V (PSB)	192	HRS	77	0
HIGH TEMP OP LIFE	1006	MAXQ1004	QS101775AB	125C, 3.6V (PSA) & 5.0V (PSB)	192	HRS	45	0
HIGH TEMP OP LIFE	1024	MAXQ1010	QJ101790AG	125C, 5.5V (PS1) & 3.6V (PS2)	192	HRS	45	0
HIGH TEMP OP LIFE	1024	MAX31782	QJ102013AC	125C, 5.5 VOLTS	192	HRS	45	0
HIGH TEMP OP LIFE	1030	MAXQ613	QJ101861CH	135C, 3.6 V (PSA)	192	HRS	45	0
HIGH TEMP OP LIFE	1050	MAXQ6831	ZN112250BC	125C, 3.6V (PSA), 1.89V (PSB) & 2.94V (PSD)	1000	HRS	48	0
HIGH TEMP OP LIFE	1111	MAXQ618	ZJ112624AD	125C, 3.6 VOLTS	192	HRS	48	0
HIGH TEMP OP LIFE	1119	MAXQ1740	ZJ112746BA	125C, 3.6 VOLTS	192	HRS	48	0
HIGH TEMP OP LIFE	1120	DS4830	ZS112802AC	125C, 3.3 VOLTS	192	HRS	77	0
HIGH TEMP OP LIFE	1134	MAXQ1050	ZS123062AB	125C, 5.5V (PSA) & 3.6V (PSB)	192	HRS	48	0
HIGH TEMP OP LIFE	1135	MAXQ610	ZJ111435FC-	125C, 3.6V (PSA) & 2.0V (PSB)	1000	HRS	77	0
HIGH TEMP OP LIFE	1135	MAXQ610	ZJ111435BD	125C, 3.6V (PSA) & 2.0V (PSB)	1000	HRS	77	0
HIGH TEMP OP LIFE	1135	MAXQ610	ZJ111438BB-	125C, 3.6V (PSA) & 2.0V (PSB)	1000	HRS	77	0
HIGH TEMP OP LIFE	1211	**MAXQ615**	ZS123275AE	125C, 3.6 VOLTS	192	HRS	80	0
					Total:			**0**

FAILURE RATE:	**MTTF (YRS):**	**55079**	**FITS:**	**2.1**	
	DEVICE HOURS:	**442104589**	**FAILS:**	**0**	

DS28E17 is built with the identical die of MAXQ615.